



N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _A = +25°C		
60V	5Ω @ V _{GS} = 10V	0.21A		
600	6Ω @ V _{GS} = 5V	0.20A		

Description

This MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

Applications

- Motor Control
- Power Management Functions

Features

- Low On-Resistance: R_{DS(ON)}
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- . ESD Protected up to 1kV
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative.

https://www.diodes.com/quality/product-definitions/

Mechanical Data

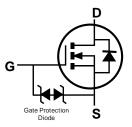
- Case: SOT523
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Alloy 42 Leadframe. Solderable per MIL-STD-202, Method 208 (§3)
- Terminal Connections: See Diagram
- Weight: 0.002 grams (Approximate)



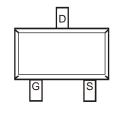


SOT523

Top View







Top View Pin Out Configuration

Ordering Information (Note 4)

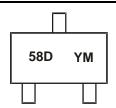
Part Number	Case	Packaging
DMN65D8LT-7	SOT523	3000/Tape & Reel
DMN65D8LT-13	SOT523	10000/Tape & Reel

Notes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3).compliant. All applicable RoHS exemptions applied.

- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



Marking Information



58D = Product Type Marking Code YM = Date Code Marking Y or \overline{Y} = Year (ex: H = 2020) M = Month (ex: 9 = September)

Date Code Key

Year	2014		:	2019	2020	2	2021	2022	202	3	2024	2025	2026	2027	2028
Code	В			G	Н		I	J	K		L	М	N	0	Р
N	Nonth	Ja	ın	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	N	ov	Dec
(Code	1		2	3	4	5	6	7	8	9	0		N	D

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Drain-Source Voltage		V _{DSS}	60	V	
Gate-Source Voltage		V_{GSS}	±20	V	
Continuous Prais Current (Note 6) // F 0//	Steady	T _A = +25°C	- I _D	210	mA
Continuous Drain Current (Note 6) V _{GS} = 5.0V	State	T _A = +70°C		170	IIIA
Maximum Continuous Body Diode Forward Currer	nt (Note 6)		Is	210	mA
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1	%)	I _{DM}	0.7	Α	
Pulsed Source Current (10µs Pulse, Duty Cycle =	1%)	I _{SM}	0.7	Α	

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)		P_{D}	300	mW
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	$R_{\theta JA}$	426	°C/W
Total Power Dissipation (Note 6)		P _D	360	mW
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	$R_{\theta JA}$	351	°C/W
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +150	°C



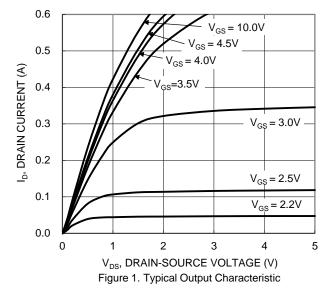
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)	-						
Drain-Source Breakdown Voltage	BV _{DSS}	60	_	_	V	$V_{GS} = 0V, I_D = 10\mu A$	
Zero Gate Voltage Drain Current	I _{DSS}	_	_	1.0	μΑ	$V_{DS} = 60V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	_	_	±10	μΑ	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V _{GS(TH)}	1.2		2.0	V	VDS = VGS, ID = 250μA	
Static Drain-Source On-Resistance	D		2.0	5.0	0	$V_{GS} = 10V, I_D = 0.115A$	
Static Drain-Source Off-Nesistance	R _{DS(ON)}		2.2	6.0	12	$V_{GS} = 5V, I_D = 0.115A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	C _{iss}	_	24	_			
Output Capacitance	Coss	_	2.8	_	pF	$V_{DS} = 25V, V_{GS} = 0V$ f = 1.0MHz	
Reverse Transfer Capacitance	C _{rss}	_	1.8	_		1 = 1.000112	
Gate Resistance	R_g	_	50	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$	
Total Gate Charge	Qg	_	0.4	_			
Gate-Source Charge	Q_{gs}	_	0.12	_	nC	$V_{DD} = 30V, V_{GS} = 4.5V, I_{D} = 150mA$	
Gate-Drain Charge	Q _{gd}	_	0.14	_			
Turn-On Delay Time	t _{D(ON)}	_	2.0	_			
Turn-On Rise Time	t _R		1.9			$V_{GS} = 10V, V_{DD} = 30V, R_g = 25\Omega,$	
Turn-Off Delay Time	t _{D(OFF)}		9.5	_	ns	$I_D = 0.2A$	
Turn-Off Fall Time	t _F		4.3	_			

Notes:

- 5. Device mounted on FR-4 PCB, with minimum recommended pad layout
 6. Device mounted on 1" x 1" FR-4 PCB with high coverage 2oz. Copper, single sided.
 7. Short duration pulse test used to minimize self-heating effect.
- 8. Guaranteed by design. Not subject to product testing.





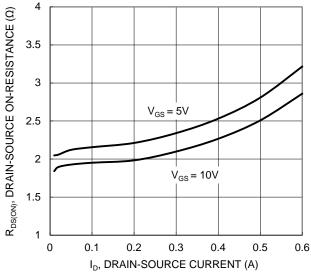


Figure 3. Typical On-Resistance vs. Drain Current and Gate Voltage

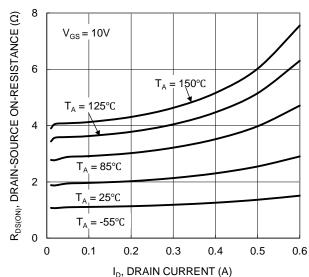
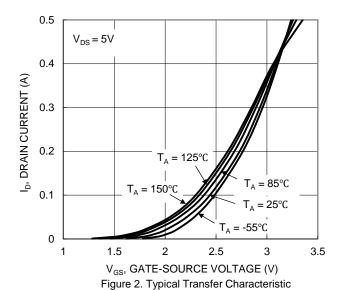
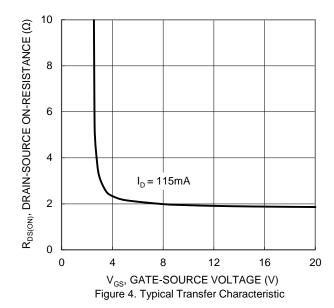


Figure 5. Typical On-Resistance vs. Drain Current and Junction Temperature





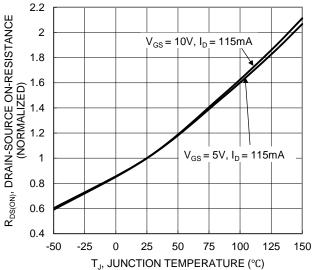


Figure 6. On-Resistance Variation with Junction Temperature



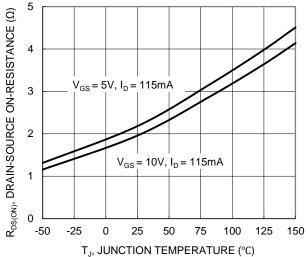
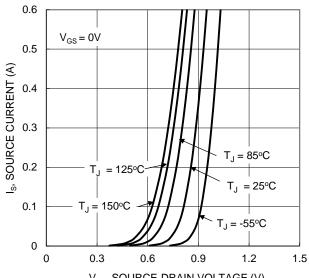


Figure 7. On-Resistance Variation with Junction Temperature



V_{SD}, SOURCE-DRAIN VOLTAGE (V) Figure 9. Diode Forward Voltage vs. Current

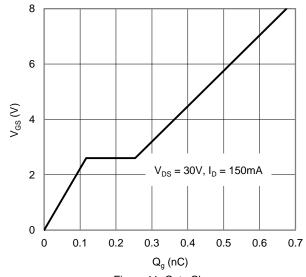


Figure 11. Gate Charge

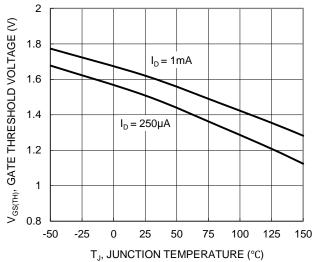


Figure 8. Gate Threshold Variation vs. Junction Temperature

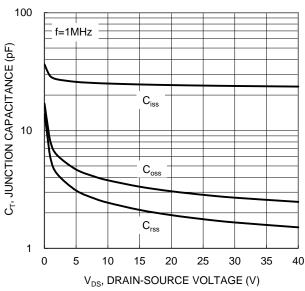


Figure 10. Typical Junction Capacitance

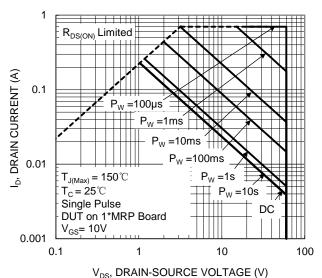


Figure 12. SOA, Safe Operation Area



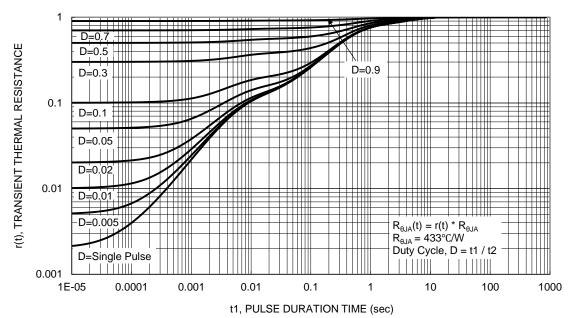


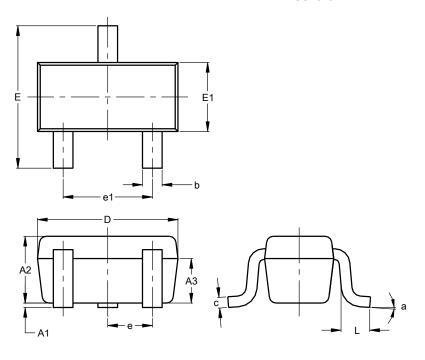
Figure 13. Transient Thermal Resistance



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT523

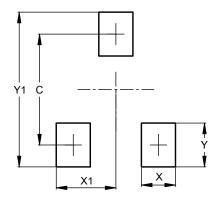


SOT523							
Dim	Min	Max	Тур				
A1	0.00	0.10	0.05				
A2	0.60	0.80	0.75				
A3	0.45	0.65	0.50				
b	0.15	0.30	0.22				
С	0.10	0.20	0.12				
D	1.50	1.70	1.60				
E	1.45	1.75	1.60				
E1	0.75	0.85	0.80				
е		0.50 BS	С				
e1	0.90	1.10	1.00				
L	0.20	0.40	0.33				
а	0°		8°				
All Dimensions in mm							

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT523



Dimensions	Value (in mm)				
C	1.29				
Х	0.40				
X1	0.70				
Y	0.51				
Y1	1.80				



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